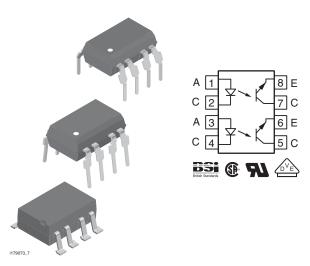


RoHS

COMPLIANT

Vishay Semiconductors

# **Optocoupler, Phototransistor Output, Dual Channel**



### DESCRIPTION

The ILD610 series is a dual channel optocoupler series for high density applications. Each channel consists of an optically coupled pair with a gallium arsenide infrared LED and silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD610 series is the dual version of SFH610 series and uses a repetitive pin-out configuration instead of the more common alternating pin-out used in most dual couplers.

### FEATURES

- Dual version of SFH610 series
- Isolation test voltage, 5300 V<sub>BMS</sub>
- V<sub>CEsat</sub> 0.25 ( $\leq$  0.4) V at I<sub>F</sub> = 10 mA, I<sub>C</sub> = 2.5 mA
- V<sub>CEO</sub> = 70 V
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

### AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884)/DIN EN 60747-5-5 pending
- CSA 93751
- BSI IEC 60950; IEC 60065

ORDERING INFORMATION							
I       L       D       6       1       0       -       #       X       0       0       #       T         PART NUMBER       CTR BIN       PACKAGE OPTION       TAPE AND REEL       Option 7       Option 9							
AGENCY CERTIFIED/PACKAGE		CTR (%)					
UL, CSA, BSI	40 to 80	63 to 125	100 to 200	160 to 320			
DIP-8	ILD610-1 -		ILD610-3	-			
DIP-8, 400 mil, option 6	-	-	ILD610-3X006	-			
SMD-8, option 7	-	ILD610-2X007T	-	-			
SMD-8, option 9	-	-	ILD610-3X009	ILD610-4X009			

#### Note

• Additional options may be possible, please contact sales office.

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# ILD610



## Vishay Semiconductors Optocoupler, Phototransistor Output, Dual Channel

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
INPUT	·	•	· ·		
Reverse voltage		V <sub>R</sub>	6.0	V	
Surge forward current	t ≤ 1.0 ms	I <sub>FSM</sub>	1.5	А	
Power dissipation		P <sub>diss</sub>	100	mW	
Derate linearly from 25 °C			1.3	mW/°C	
Forward continuous current		IF	60	mA	
OUTPUT					
Collector emitter voltage		V <sub>CE</sub>	70	V	
Collector current		Ι <sub>C</sub>	50	mA	
	$t \le 1.0 \text{ ms}$	Ι <sub>C</sub>	100	mA	
Power dissipation		P <sub>diss</sub>	150	mW	
Derate linearly from 25 °C			2.0	mW/°C	
COUPLER					
Isolation test voltage	t = 1.0 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>	
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω	
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω	
Storage temperature		T <sub>stg</sub>	- 55 to + 150	°C	
Operating temperature		T <sub>amb</sub>	- 55 to + 100	°C	
Junction temperature		Tj	100	°C	
Lead soldering time at 260 °C			10	S	

### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I <sub>F</sub> = 60 mA		VF		1.25	1.65	V	
Reverse current	$V_{R} = 6.0 V$		I <sub>R</sub>		0.01	10	μA	
Capacitance	V <sub>R</sub> = 0 V, f = 1.0 MHz		Co		25		pF	
OUTPUT								
Collector emitter breakdown voltage	l <sub>C</sub> = 10 mA, l <sub>E</sub> = 10 μA		BV <sub>CEO</sub>	70	90		V	
			BV <sub>CEO</sub>	6.0	7.0		V	
Collector emitter dark current	$V_{CE} = 10 V$		I <sub>CEO</sub>		2.0	50	nA	
Collector emitter capacitance	$V_{CE} = 5.0 \text{ V}, \text{ f} = 1.0 \text{ MHz}$		C <sub>CE</sub>		7.0		pF	
Collector emitter leakage current	V <sub>CE</sub> = 10 V	ILD610-1	I <sub>CEO</sub>		2.0	50	nA	
		ILD610-2	I <sub>CEO</sub>		2.0	50	nA	
		ILD610-3	I <sub>CEO</sub>		5.0	100	nA	
		ILD610-4	I <sub>CEO</sub>		5.0	100	nA	
COUPLER								
Collector emitter saturation voltage	$I_F = 10$ mA, $I_C = 2.5$ mA		V <sub>CEsat</sub>		0.25	0.40	V	
Coupling capacitance			C <sub>C</sub>		0.35		pF	

### Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

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## Optocoupler, Phototransistor Output, Dual Vishay Semiconductors Channel

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
CTR <sup>(1)</sup>	I <sub>F</sub> = 10 mA, V <sub>CE</sub> = 5.0 V	ILD610-1	CTR	40		80	%	
		ILD610-2	CTR	63		125	%	
		ILD610-3	CTR	100		200	%	
		ILD610-4	CTR	160		320	%	
		ILD610-1	CTR	13			%	
		ILD610-2	CTR	22			%	
	$v_{\rm F} = 1.0$ mA, $v_{\rm CE} = 5.0$ V	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$ ILD610-3 (	CTR	34			%	
		ILD610-4	CTR	56			%	

Note

<sup>(1)</sup> CTR will match within a ratio of 1.7:1

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED			11				
Rise time		ILD610-1	- t <sub>r</sub>		2.0		
	$V_{CC} = 5.0 \text{ V}, \text{ R}_{\text{I}} = 75 \Omega,$	ILD610-2			2.5		
	$I_{\rm F} = 10  {\rm mA}$	ILD610-3			2.9		μs
		ILD610-4			3.3		
		ILD610-1			2.0		
Fall time	$V_{CC} = 5.0 \text{ V}, \text{ R}_{L} = 75 \Omega,$	ILD610-2	t <sub>f</sub>		2.6		
raii ume	I <sub>F</sub> = 10 mA	ILD610-3			3.1		μs
		ILD610-4			3.5		
		ILD610-1	t <sub>on</sub>		3.0		
Turn-on time	$V_{CC} = 5.0 \text{ V}, \text{ R}_{L} = 75 \Omega,$	ILD610-2			3.2		
	I <sub>F</sub> = 10 mA	ILD610-3			3.6		μs
		ILD610-4			4.1		
		ILD610-1	- t <sub>off</sub>		2.9		
Turn off times	$V_{CC} = 5.0 \text{ V}, \text{ R}_{L} = 75 \Omega,$	ILD610-2			3.4		
Turn-off time	$I_F = 10 \text{ mA}$	ILD610-3			3.7		μs
		ILD610-4			4.1		
SATURATED		•			•		
	$V_{CC} = 5.0 \text{ V}, \text{ R}_L = 1.0 \text{ k}\Omega, \text{ I}_F = 20 \text{ mA}$	ILD610-1	- t <sub>r</sub>		2.0	_	
Diag time	$V_{CC} = 5.0 \text{ V}, \text{ R}_L = 1.0 \text{ k}\Omega, \text{ I}_F = 10 \text{ mA}$	ILD610-2			2.8		
Rise time	$V_{CC} = 5.0 \text{ V}, \text{ R}_L = 1.0 \text{ k}\Omega, \text{ I}_F = 10 \text{ mA}$	ILD610-3			2.8		μs
	$V_{CC} = 5.0 \text{ V}, \text{ R}_{L} = 1.0 \text{ k}\Omega, \text{ I}_{F} = 5 \text{ mA}$	ILD610-4			4.6		
	$V_{CC} = 5.0 \text{ V}, \text{ R}_L = 1.0 \text{ k}\Omega, \text{ I}_F = 20 \text{ mA}$	ILD610-1			11		
Fall time	$V_{CC} = 5.0 \text{ V}, \text{ R}_L = 1.0 \text{ k}\Omega, \text{ I}_F = 10 \text{ mA}$	ILD610-2	t <sub>f</sub>		14		
	$V_{CC} = 5.0 \ V, \ R_L = 1.0 \ k\Omega, \ I_F = 10 \ mA$	ILD610-3			14		μs
	$V_{CC}=5.0~V,~R_L=1.0~k\Omega,~~I_F=5~mA$	ILD610-4			15		
	$V_{CC} = 5.0 \text{ V}, \text{ R}_L = 1.0 \text{ k}\Omega, \text{ I}_F = 20 \text{ mA}$	ILD610-1			3.0		μs
Turn-on time	$V_{CC} = 5.0 \ V, \ R_L = 1.0 \ k\Omega, \ I_F = 10 \ mA$	ILD610-2	t <sub>on</sub>		4.3		
rum-on time	$V_{CC} = 5.0 \text{ V}, \text{ R}_L = 1.0 \text{ k}\Omega, \text{ I}_F = 10 \text{ mA}$	ILD610-3			4.3		
	$V_{CC}=5.0~V,~R_L=1.0~k\Omega,~~I_F=5~mA$	ILD610-4			6.0		
	$V_{CC} = 5.0 \text{ V}, \text{ R}_{L} = 1.0 \text{ k}\Omega, \text{ I}_{F} = 20 \text{ mA}$	ILD610-1			18		
Turn off time	$V_{CC}$ = 5.0 V, $R_L$ = 1.0 k $\Omega$ , $I_F$ = 10 mA	ILD610-2	t <sub>off</sub>		25		
Turn-off time	$V_{CC} = 5.0 \; V, \; R_L = 1.0 \; k\Omega, \;\; I_F = 10 \; mA$	ILD610-3			25		μs
	$V_{CC} = 5.0 \text{ V}, \text{ R}_{L} = 1.0 \text{ k}\Omega, \text{ I}_{F} = 5 \text{ mA}$	ILD610-4			25	1	

For technical questions, contact: optocoupler.answers@vishay.com

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## **ILD610**



## Vishay Semiconductors Optocoupler, Phototransistor Output, Dual Channel

### TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

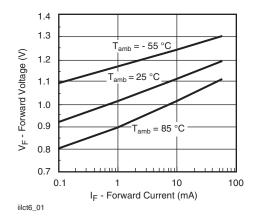


Fig. 1 - Forward Voltage vs. Forward Current

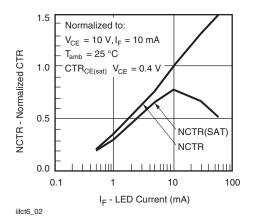


Fig. 2 - Normalized Non-Saturated and Saturated CTR vs. LED Current

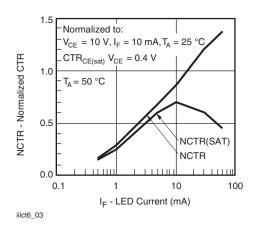


Fig. 3 - Normalized Non-Saturated and Saturated CTR vs. LED Current

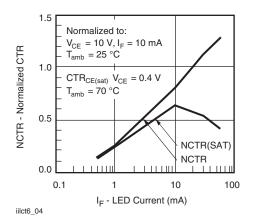


Fig. 4 - Normalized Non-Saturated and Saturated CTR vs. LED Current

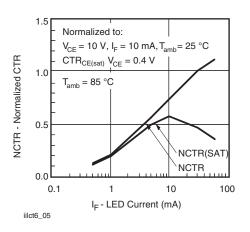


Fig. 5 - Normalized Non-Saturated and Saturated CTR vs. LED Current

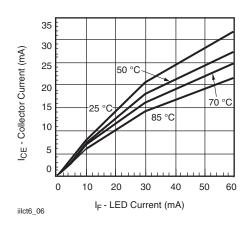


Fig. 6 - Collector Emitter Current vs. Temperature and LED Current

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Optocoupler, Phototransistor Output, Dual Vishay Semiconductors Channel

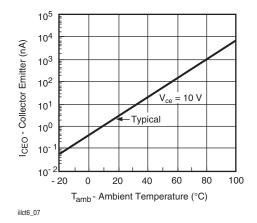
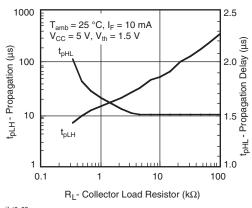


Fig. 7 - Collector Emitter Leakage Current vs.Temperature



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Fig. 8 - Propagation Delay vs. Collector Load Resistor

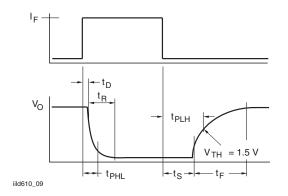


Fig. 9 - Switching Timing

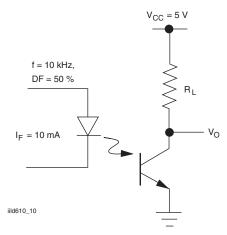
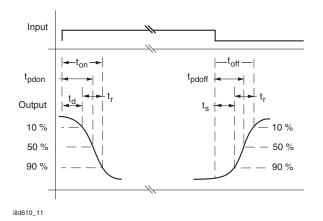


Fig. 10 - Non-Saturated Switching Schematic





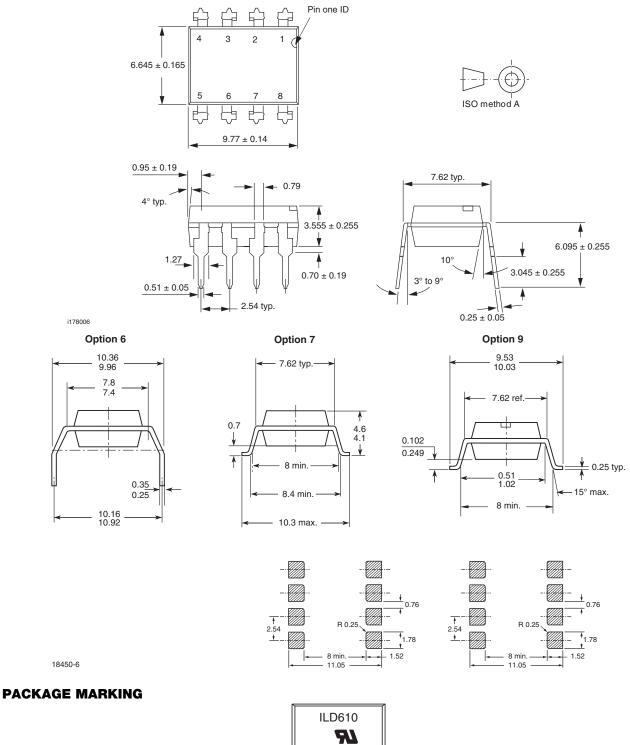
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## **ILD610**

Vishay Semiconductors Optocoupler, Phototransistor Output, Dual Channel

### **PACKAGE DIMENSIONS** in millimeters



Notes

- Only option 1 and 7 reflected in the package marking •
- Tape and reel suffix (T) is not part of the package marking

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